# Mobile용 PMIC 설계

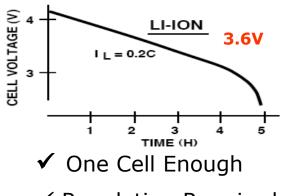
## 2010년도 AIPRC Power IC 설계 기술 Workshop

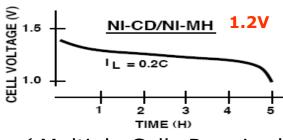
2010년 12월 9일

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## **Power Sources for Mobile Devices**

#### Typical Battery Characteristics





✓ Multiple Cells Required

- ✓ Regulation Required
- Various Power Supply Voltages for ICs
  - O Supply Voltage Values (Even Negative Polarity)
  - O Load Current Amount to be Used
  - O Noise Immunity
  - Sensitivity to Load and Line Variations
  - For Different Functional Blocks

## **PMIC for Mobile Applications**

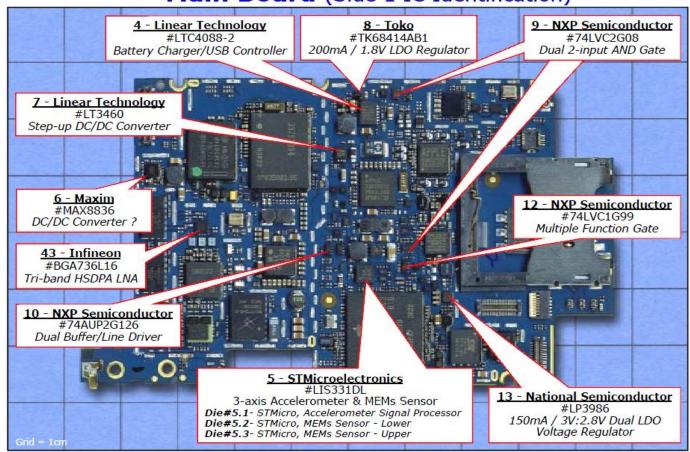
- Small Form-Factor
  - → External Inductors, Capacitors, Resistors ...
  - → Increased Operating Frequency & Bandwidth
- Reducing The Number of External Off-Chip Components
  - → Proper Topology to be Adopted
  - → New Techniques to be Studied
- Integration of Various Power Sources into Single Chip
  - → Complexity & Interference
  - → Proper IC Fabrication Technology

Difficulties in IP Integration

- Longer Battery Time : Low-Power Design
- Multi-Channel Application : Matching Important
- Multi-Functions Available Through Digital Control

## Apple iPhone 3G Example

Main Board (Side 1 IC Identification)



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Apple 3G iPhone 11000-080711-BCg - Page 2

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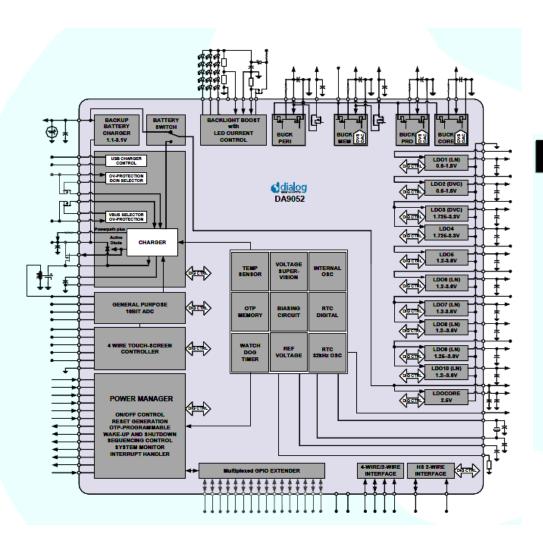
## **Apple iPhone 4 Example**



http://www.umbtechinsights.com



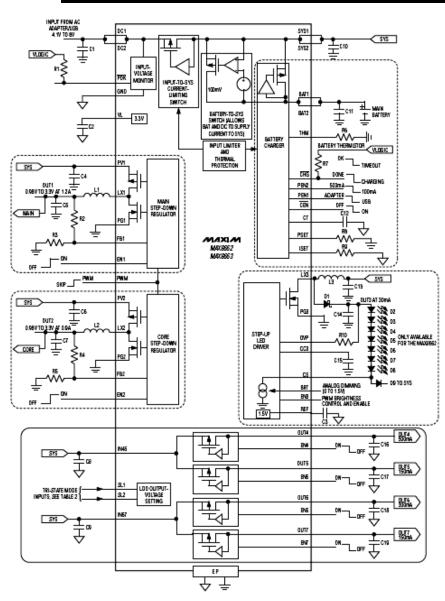
## DA9502 (Dialog-Semi) Example



#### **Features**

- Switched DC/USB Charger with power path management
- 4 DVS Buck Converters 0.5V-3.6V up to 1Amp
- 10 Programmable LDO's High PSRR, 1% ассигасу.
- Low power Backup Charger 1.1-3.1V up to 6mA
- 32kHz RTC Oscillator
- General Purpose ADC with touch screen interface
- High voltage White LED driver 24V/50Ma Boost, 3 strings
- 16 bit GPIO bus for enhanced wakeup and peripheral control
- Dual serial control interfaces
- Unique ID code capability with OTP memory

## MAX8662 (Maxim) Example



 Two 95%-Efficient 1MHz DC-DC Buck Converters

• Main: 0.98V to VIN at 1200mA

O Core: 0.98V to VIN at 900mA

1MHz Boost WLED Driver

O Up to 7 White LEDs at 30mA (max)

O PWM and Analog Dimming Control

▶ Four Low-Dropout Linear Regulators

O 1.7V to 5.5V Input Range

O 15µA Quiescent Current

Single-Cell Li+ Charger

O Adapter or USB Input

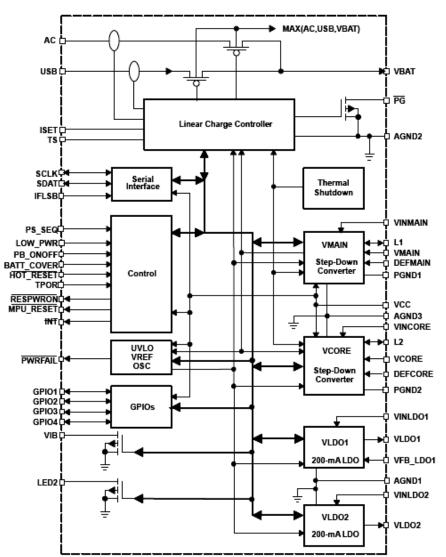
O Thermal-Overload Protection

Smart Power Selector (SPS)

• AC Adapter/USB or Battery Source

• Charger-Current and System-Load Sharing

## TPS65011 (TI) Example



- Linear Charger Management for Single Li-Ion or Li-Polymer Cells
- Dual Input Ports for Charging From USB or Wall Plug, (100/500-mA USB Req.)
- 1-A, 95% Efficient Step-Down Converter for I/O and Peripheral Components (VMAIN)
- 400-mA, 90% Efficient Step-Down Converter for Processor Core
- 2x 200-mA LDOs for I/O and Peripheral Components
- Serial Interface Compatible w/ I<sup>2</sup>C
- 100-kHz, 400-kHz Operation
- ◆ 70-µA Quiescent Current
- 1% Reference Voltage
- Thermal Shutdown Protection

## **Typical Power Source Options**

	Applications	Efficiency	Cost	Noise
LDO* Linear Regulator	$V_{OUT} < V_{IN}$	С	А	А
Charge Pump Converter**	$V_{OUT} > < V_{IN}$	В	С	С
DC-DC Boost Converter	$V_{OUT} > V_{IN}$	А	C-	C-
DC-DC Buck Converter	$V_{OUT} < V_{IN}$	А	C-	C-
DC-DC Buck/Boost Converter	$V_{OUT} > < V_{IN}$	A-	C-	C-

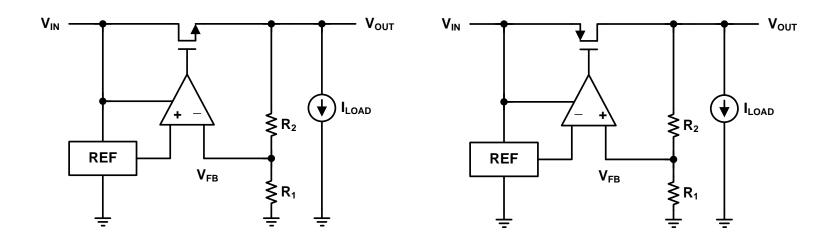
<sup>\*</sup> LDO: Low-Drop Out

#### Optimum Power Management Required

<sup>\*\*</sup> Limited Output Voltage Values & Load Current

# LDO Linear Regulator

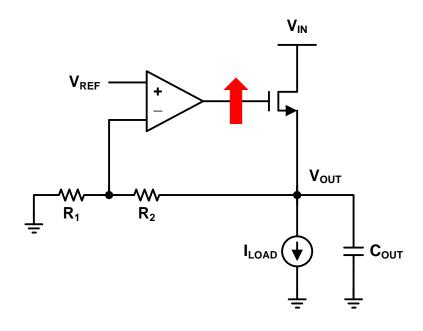
## **Linear Regulator Basic Principle**



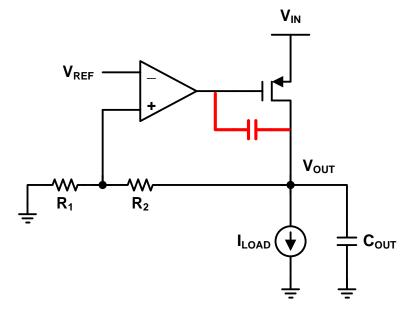
- Error Amplifier, Pass Transistor (Output Transistor), Voltage
  Reference, Feedback Network
- V<sub>GS</sub> of Pass Transistor Controlled by Error Amplifier for Defined V<sub>DS</sub>
- Output Voltage Regulated w.r.t. Varying V<sub>IN</sub> and I<sub>LOAD</sub>
- Stable Operation Required
- Efficiency  $\eta$  (ideal) =  $(V_{IN}-V_{OUT})/V_{IN}$

## **Low-Drop Out Design Restriction**

#### OUTPUT NMOSFET



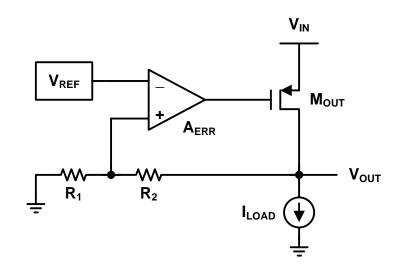
OUTPUT PMOSFET



- More Stable Operation
- Difficult for LDO Design

- Easy for LDO Design
- Less Stable Operation

## **Static Performance**



Feedback Gain

$$\beta \equiv \frac{R_1}{R_1 + R_2}$$

Loop Gain

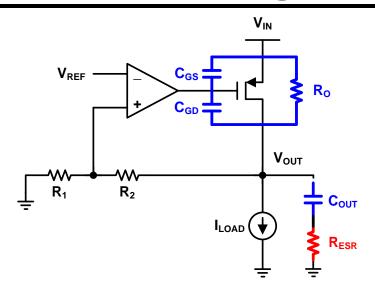
$$A_{LG} = A_{ERR} \cdot A_{M_{OUT}} \cdot \beta$$

• Transfer Function 
$$\frac{V_{OUT}}{V_{REF}} = \frac{A_{ERR} \cdot A_{M_{OUT}}}{1 + A_{LG}} \approx \frac{1}{\beta} = 1 + \frac{R_2}{R_1}$$

$$\frac{\Delta V_{OUT}}{\Delta I_{OUT}} = R_{OUT} = \frac{r_{out}|_{M_{OUT}}}{1 + A_{LG}} \approx \frac{1}{A_{ERR} \cdot g_{m}|_{M_{OUT}}} \cdot \beta$$

• Line Regulation 
$$\frac{\Delta V_{OUT}}{\Delta V_{IN}} = g_{m} \big|_{M_{OUT}} \cdot R_{OUT} = g_{m} \big|_{M_{OUT}} \cdot \frac{r_{out} \big|_{M_{OUT}}}{1 + A_{I,G}} \approx \frac{1}{A_{ERR} \cdot \beta}$$

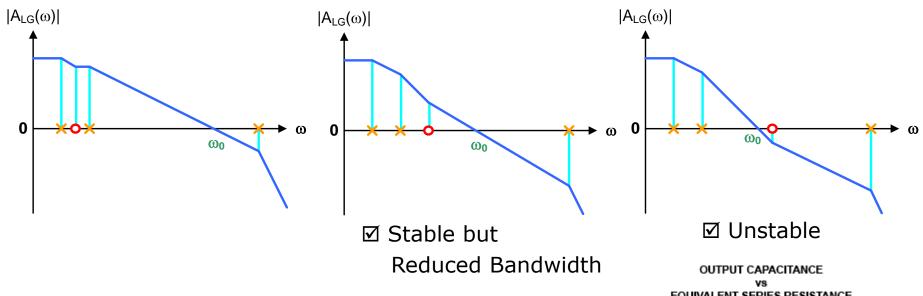
## Poles of LDO Regulator



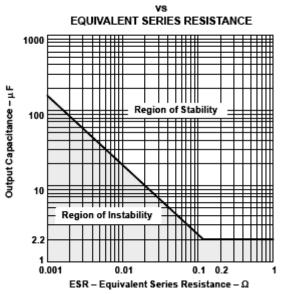
- Error Amp Output → Related w/ Large C<sub>GS</sub> & C<sub>GD</sub>
- Output Node  $\rightarrow$  Related w/ Varied  $R_0$  & Very Large  $C_{OUT}$
- Other Parasitic Capacitance Related Poles (High-Frequency)
- For Easiest Frequency Compensation, Use the Capacitor ESR (Equivalent Series Resistance)

$$\omega_{\rm ZERO} = \frac{1}{R_{\rm ESR} C_{\rm OUT}}$$

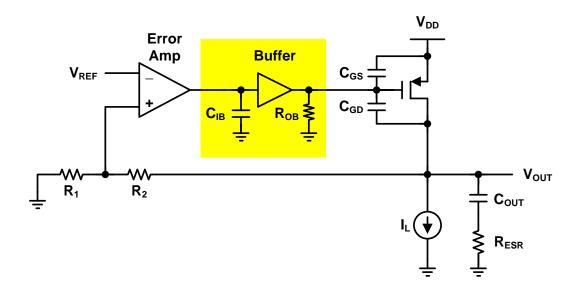
# **Limited Usage of ESR**



- As R<sub>ESR</sub> Smaller (Zero Increased)
  - → Unstable
- Limited Value of R<sub>ESR</sub> for Fixed C<sub>OUT</sub>
- As R<sub>ESR</sub> Increased
  - → Larger Perturbation during Transient



## 3-Stage LDO Regulator



- Pole @ Error Amp Output
- $1/(r_{oERR}C_{IB}) > 1/(r_{oERR}C_{MOUT})$
- → Helpful for Large Zero (Smaller R<sub>ESR</sub>)
- Pole @ Buffer Output

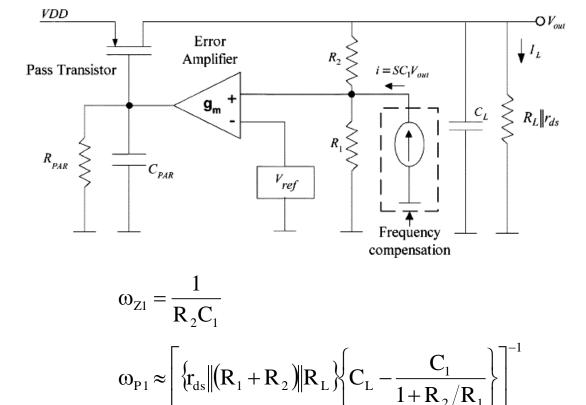
 $1/(R_{OB}C_{MOUT}) \rightarrow Large Enough$ 

• Pole @ LDO Output

 $1/(R_{OUT}C_{OUT})$ 

Parasitic Pole

## **Compensation w/ Differentiator**



$$\omega_{P2} \approx \left[ R_{par} \left\{ C_{par} + g_{mpass} \left( r_{ds} || (R_1 + R_2) || R_L \right) C_{gdpass} \right\} \right]^{-1}$$

☐ IEEE TCAS-I, pp.1041-1050, 2004 (Texas A&M Univ.)

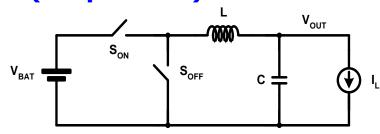
## **Design Considerations**

- Non-Idealities
  - O Limited Loop Gain for Stability
  - Accuracy of Reference Voltage
  - O Offset Voltage of Error Amplifier → Severe for Low V<sub>REF</sub>
  - Temperature Variation
- High-Performance Required
  - Reduced Standby Current Consumption
  - Fast Transient Operation
  - Improved Line/Load Regulation
  - O Large Output Transistor for Higher Current Capability
  - O Handling of Large Dynamic Switching Load Current
  - O Possible Lack of External Capacitor

# DC-DC Converter

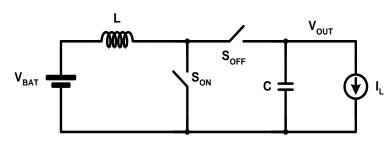
## **DC-DC Converter Basic**

Buck (Step-Down) Converter



$$\begin{cases} s_{off} & c = \frac{1}{T} \\ v_{OUT} & c = \frac{T_{ON}}{T} \\ v_{BAT} & c = \frac{T_{ON}}{T} \end{cases}$$

Boost (Step-Up) Converter

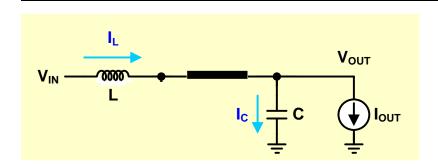


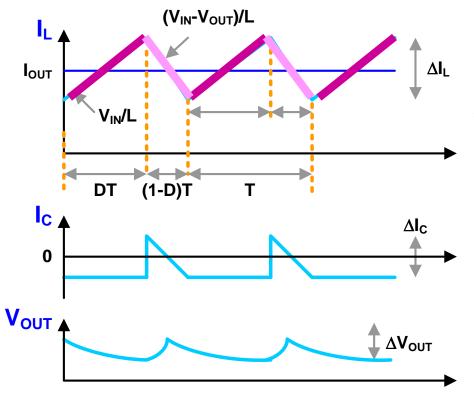
$$V_{OUT} = \frac{1}{1-D} V_{BAT} = \frac{T}{T_{OFF}} V_{BAT}$$

Buck/Boost Converter

$$V_{OUT} = \frac{D}{1-D} V_{BAT} = \frac{T_{ON}}{T_{OFF}} V_{BAT}$$

### **Boost Converter Basic**





On-Time : DT

$$\Delta I_L|_{ON} = \frac{1}{L} \int_{DT} V_L(t) dt = \frac{V_{IN}}{L} DT$$

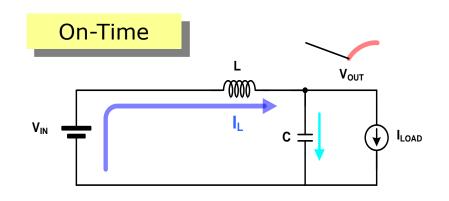
- → Store Energy in Inductor
- Off-Time: (1-D)T

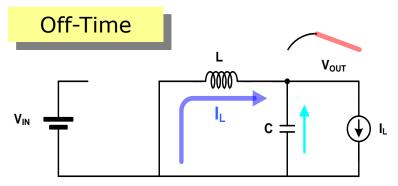
$$\Delta I_{L}|_{OFF} = \frac{1}{L} \int_{(1-D)T} V_{L}(t) dt = \frac{V_{IN} - V_{OUT}}{L} (1-D)T$$

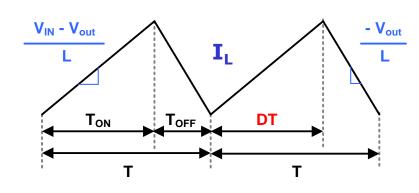
- → Provide I<sub>OUT</sub>
- → Maintain V<sub>OUT</sub>
- @ Steady Stage

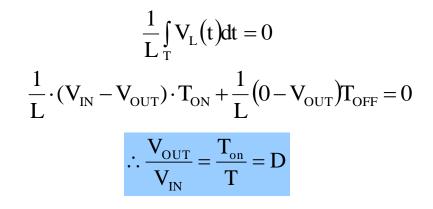
$$V_{OUT} = \frac{1}{1 - D} V_{IN}$$

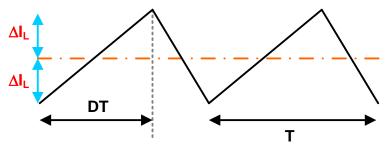
## **Buck Converter @ Steady State**





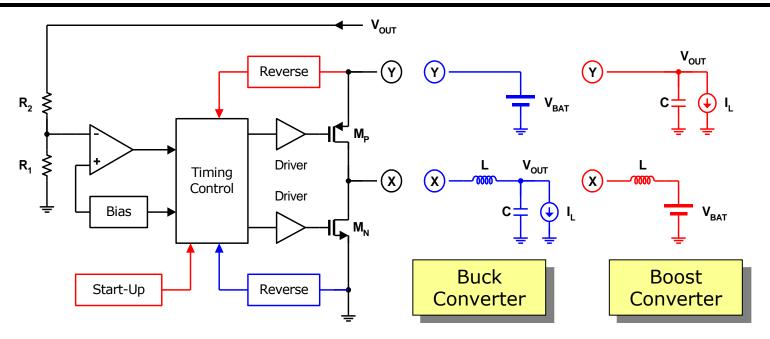






$$2\Delta I_{L} = \frac{V_{IN} - V_{OUT}}{L} \cdot T_{ON} = \frac{V_{IN} - V_{OUT}}{L} \cdot DT$$
$$\therefore \Delta I_{L} = \frac{V_{IN} - V_{OUT}}{2L} \cdot DT$$

### **Architecture**



- Large MOSFET Switches  $\rightarrow$  R<sub>ON</sub> << 100m $\Omega$
- Timing Control Circuit for Frequency / Duty-Cycle Programming
- Negative Feedback Circuit to Maintain a Output Voltage
- Frequency Compensation for Stable Operation
- Driver Circuits for Driving Large MOSFET Switches
- Protection & Start Up Circuitry

# **Efficiency** η

• Efficiency  $\eta$ :  $P_{\text{output}} / P_{\text{battery}} = (P_{\text{battery}} - P_{\text{loss}}) / P_{\text{battery}}$ 

#### Power Loss

- ✓ Conduction Loss
  - → Load Current Dependent
  - → On-Switch Resistance, DCR of Inductor, ESR of Capacitor
  - → Large MOSFET Switches, Good External Components

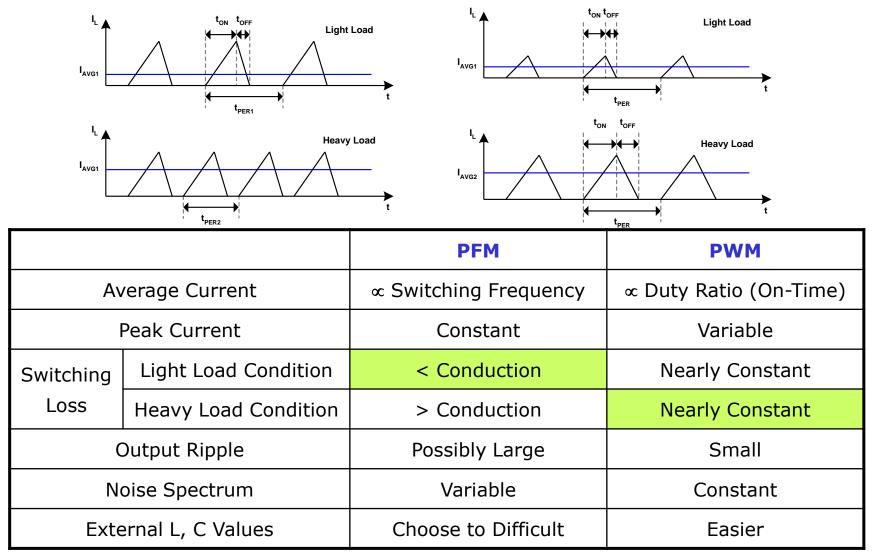
#### ✓ Switching Loss

- → Frequency Dependent
- → Switching Active Devices, Charging Capacitors
- → Low-Frequency Desirable (Limited by I<sub>PEAK</sub>)

#### **✓** Fixed Loss

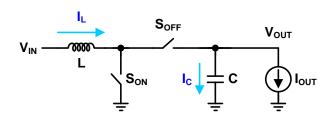
- → Bias Current, Leakage Current
- → Low-Power Design

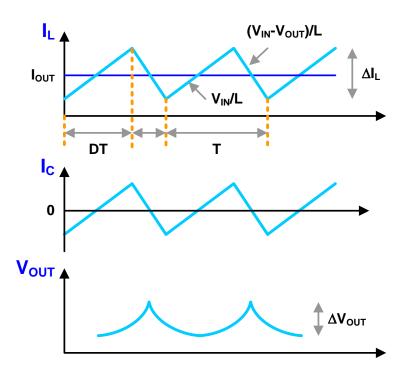
### PWM vs. PFM



Preferred Approach of Combining Both Modulations

## **Switching Frequency**





Inductor Current Ripple

$$\Delta I_{L} = \frac{V_{IN}}{L}DT = \frac{V_{IN} - V_{OUT}}{L}(1-D)T$$

For CCM Operation

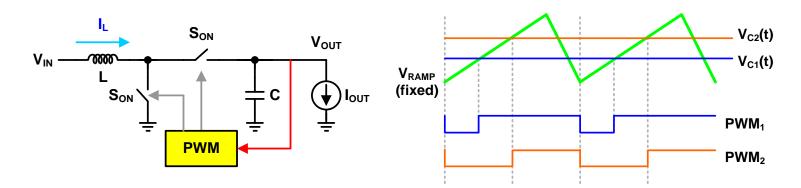
$$I_{OUT} > \frac{\Delta I_L}{2} \Longrightarrow L > \frac{1}{2} \frac{R_{OUT}}{f} D(1-D)$$

Output Voltage Ripple

$$\Delta V_{\text{OUT}} \cong \frac{D(1-D)V_{\text{OUT}}}{8LC} \frac{1}{f^2}$$

- Higher Switching Frequency
  - → Smaller L & C Needed
  - → Preferred for Mobile
  - → High-Speed Switching FETs?

# Voltage-Mode PWM Controller (1)



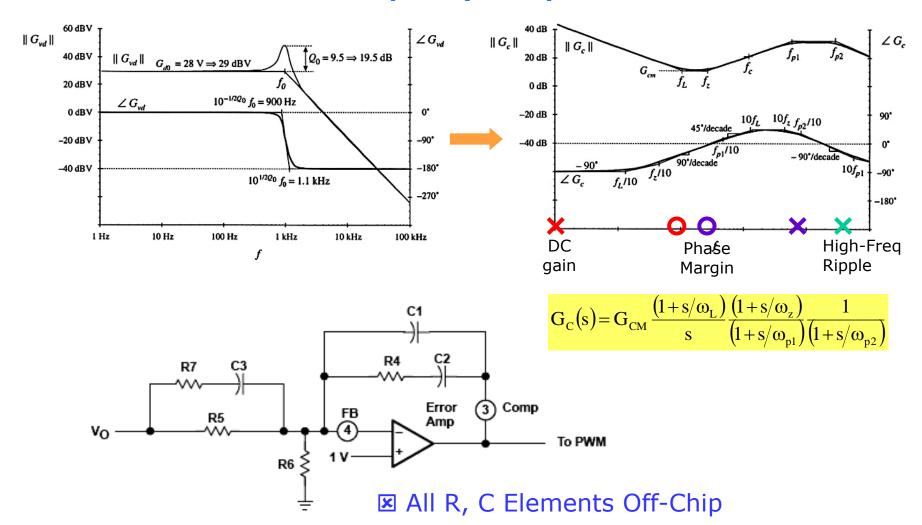
- Output Voltage Used for Generating PWM Signal
- Advantage : Simplicity
- Control-to-Output Transfer Function (Boost)

$$H_{C}(s) = \left(\frac{V_{OUT}}{1-D}\right) \frac{1 - \frac{L}{(1-D)^{2}R}s}{1 + \frac{L}{(1-D)^{2}R}s + \frac{(1-D)^{2}}{LC}s^{2}}$$

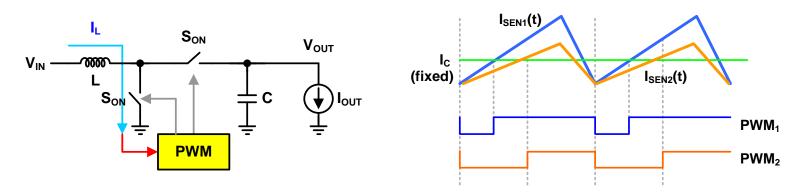
- Unstable When Used in Feedback
  - → Elaborate Frequency Compensation Required

# Voltage-Mode PWM Controller (2)

#### **PID Frequency Compensation**



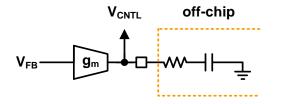
## **Current-Mode PWM Controller (1)**



- Inductor Current Used for Generating PWM Signal
- Control-to-Output Transfer Function (Boost)

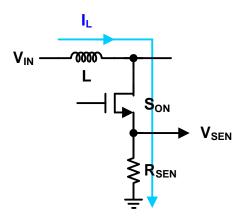
$$H_{C}(s) \approx \frac{(1-D)R}{2} \frac{1 - \frac{L}{(1-D)^{2}R}s}{1 + \frac{RC}{2}s}$$

Simple Compensation → Useful for Mobile Application

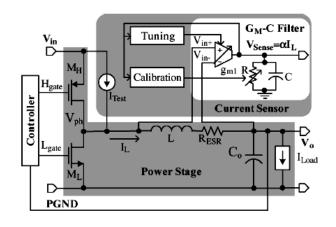


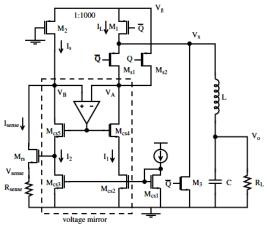
$$\frac{1}{1 - sRC} = g_m \frac{1 + sRC}{sC}$$

## **Current-Mode PWM Controller (2)**



- Simple
- Degraded Efficiency
- Off-Chip Resistor

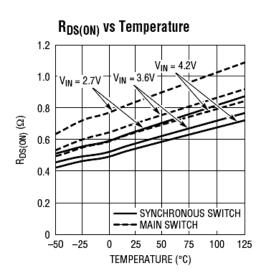


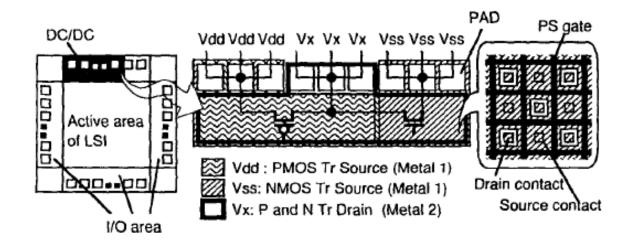


- Current-Mirroring
- On-Chip Current Sensing
- Mismatch Problem?
  - ☐ *IEEE JSSC*, 2004
- Inductor Current Simulation
- On-Chip Current Sensing
- Tuning & Calibration ?
  - ☐ *IEEE JSSC*, 2007

## **Integrated Power Switch Transistors**

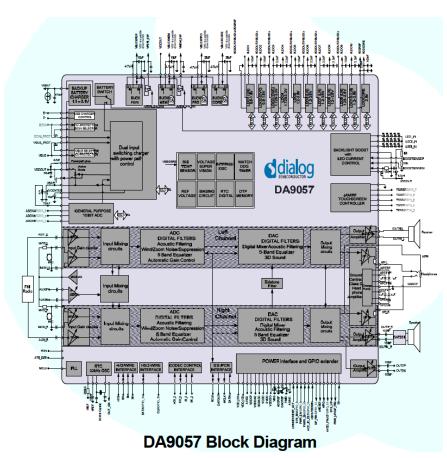
- Conduction Power Loss  $\rightarrow$  P =  $I^2R$
- If Possible, Synchronous Two Switches to be Integrated
- R<sub>ON</sub>: Transistor ON Resistance
  - $\rightarrow$  Large Size : W>100,000µm for Several 10m $\Omega$
  - → Preferred Structure : High Width-to-Area Ratio





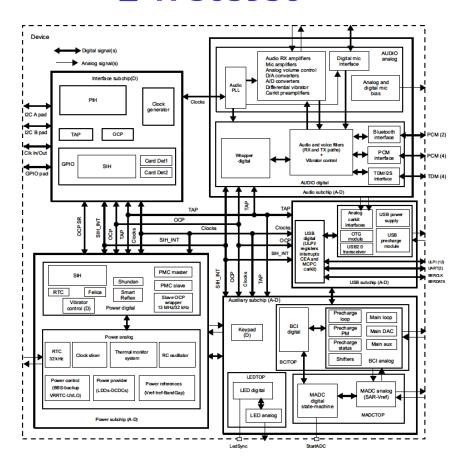
### **PMIC** + $\alpha$

#### □ DA9057



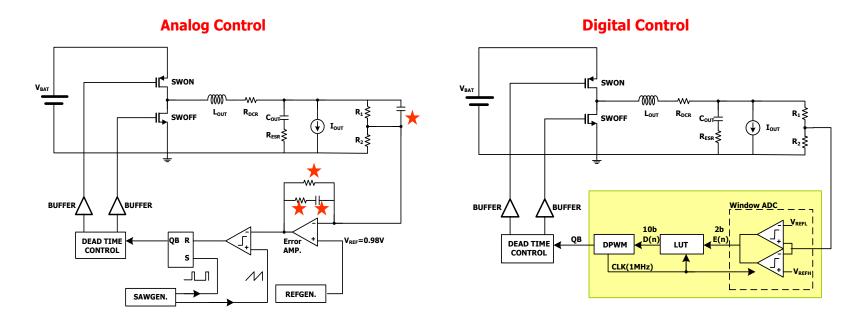
DC/USB Chrg, 4 Bucks, 10 LDOs, w-LED, 16-b Stereo CODEC, 5-band EQ

#### ☐ TPS65950



DC/USB Chrg, 3 Bucks, 10 LDOs, w-LED, Voice/Linear CODECs, 16-b ADC/DAC, Audio I/O, USB Tx/Rx

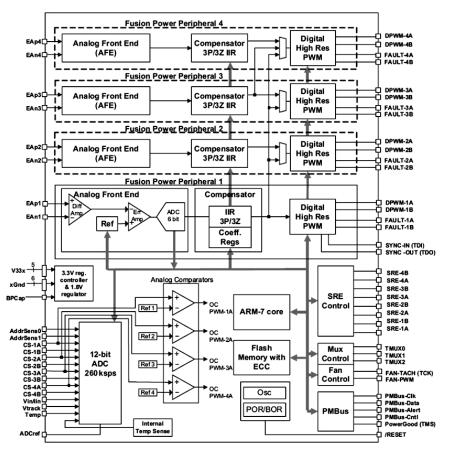
## **Digital PWM Controller Approach**



- Digital Controller to Simulate Analog Frequency Compensator
  - → External R & C Components to be Removed
- ◆ Hardware Minimization → 2-bit ADC, Look-Up Table Approach
  Digital PWM w/ Error Feedback Loop
- Digital Versatility?

## **Digital PMIC Example**

#### **□** UCD9240 of TI



- Digital Power Control/Management
- Digital Power Control
  - Reference Setting
  - Compensation Algorithm
  - O DPWM Control
- DPWM w/ Various Operating Modes
- V/I/Temp Sensing w/ ADCs
- V/I/Temp Protection
- PMBus for External Interfacing

# 감사합니다.

# Q & A

